

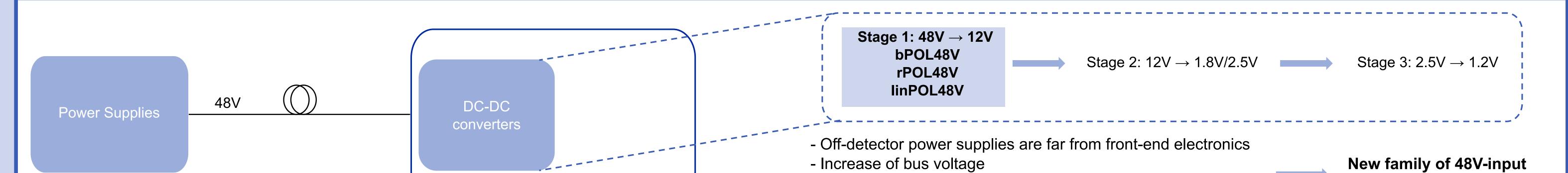
bPOL48V, rPOL48V and linPOL48V: 48V-input-rated rad-hard POL converters for HEP experiments

WP5.2 EP R&D

P. Antoszczuk¹, S. Michelis¹, G. Ripamonti¹, M. Balutto², S. Saggini², F. Iob²

¹ CERN EP-ESE-ME, ² University of Udine

TWEPP-22



bPOL48V

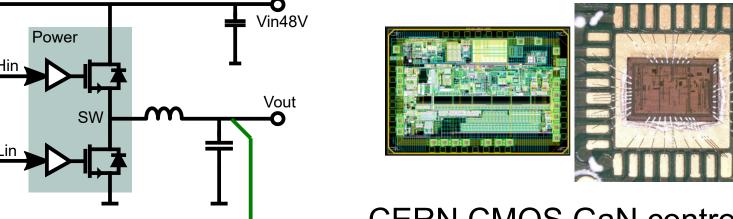


Block diagram

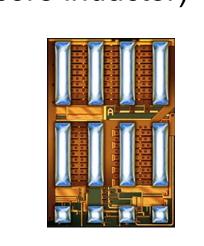
Control

Key features:

- Buck converter
- GaN commercial ePower power stage
- CMOS CERN rad-hard controller
- 48V input, 12V regulated output- 10A maximum load (120W)
- High efficiency- 49mm x 43mm x 25mm (with air core inductor)



CERN CMOS GaN controller layout and chip-on-board. Final package is QFN32.



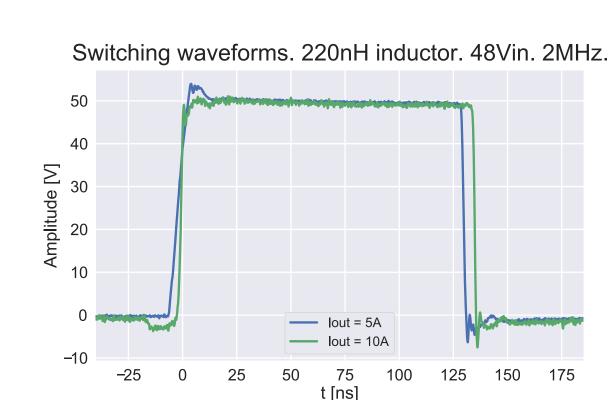
Detector (high radiation)

GaN ePower stage

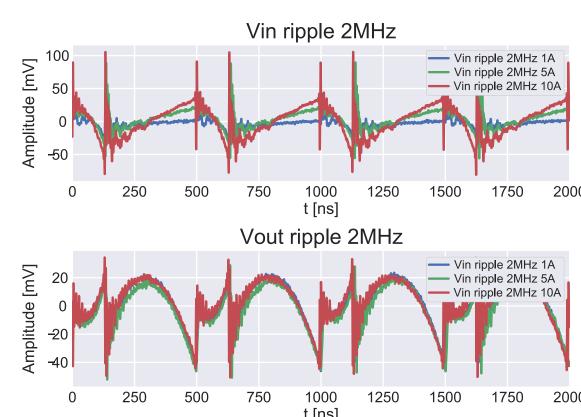
Electrical characterization

- Reduction of wiring requirements (losses, weight and cost)

- Reduction of powering complexity (Point-of-Load regulation)



trise = 2ns - fall = 1ns
No ringing above Vin
(low inupt loop parasitics)



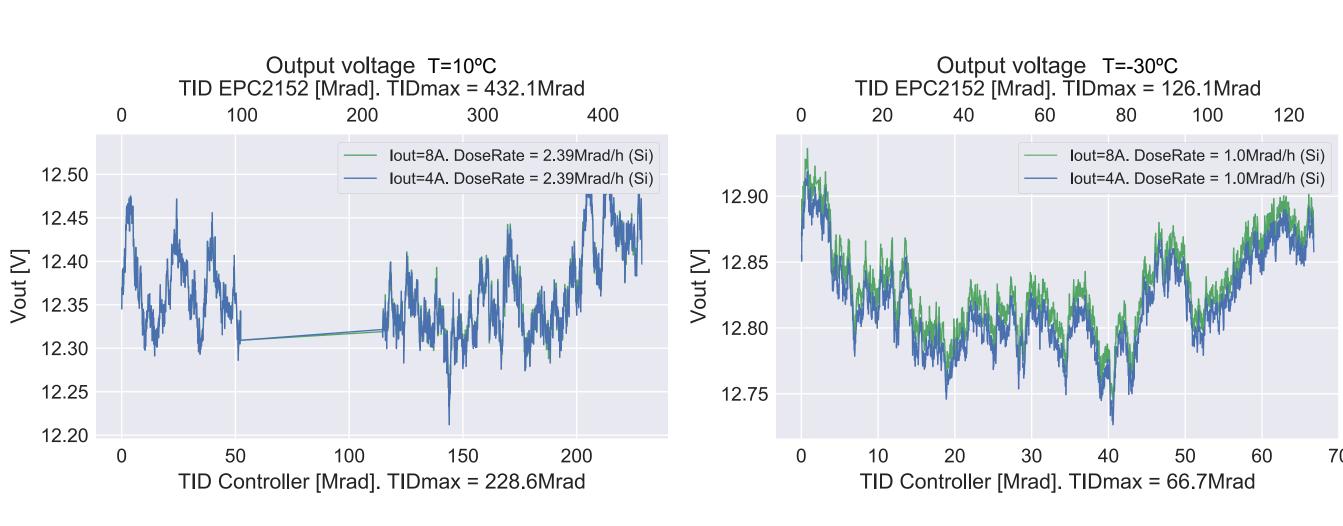
converters required

ΔVin < 80mV (0.17% at 48V, 10A) ΔVout < 60mV (0.5% at 12V)

97.5 95.0 99.0 99.0 87.5 85.0 82.5 80.0 2 4 6 8 10 12 lout [A]

Efficiency greater than 92% at nominal conditions

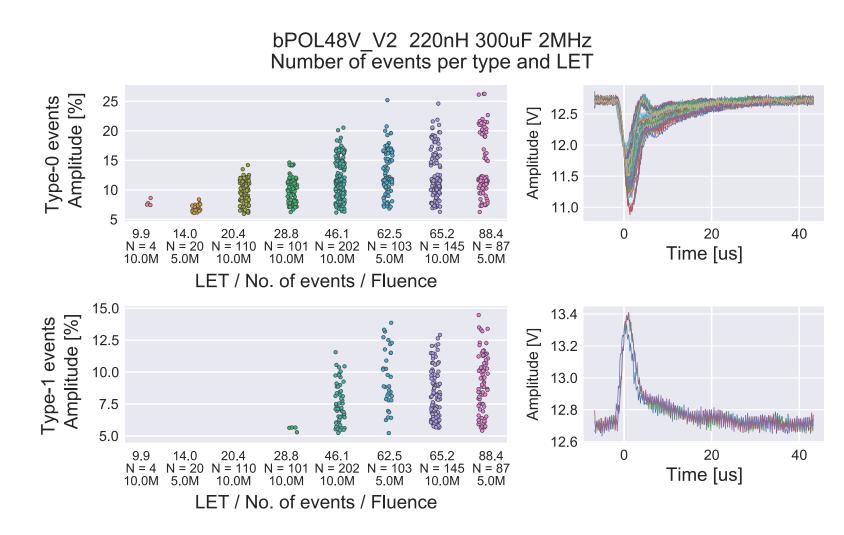
Radiation characterization



TID tested using x-ray.

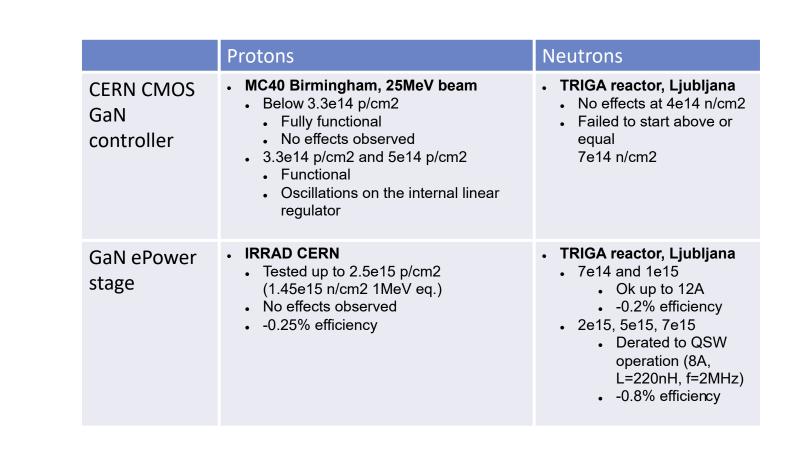
Temperature of bottom plate = 10°C (left) and -30°C (right)

No degradation of perfomance observed. Variables such as efficiency, internal regulators, proportional-to-absolute temperature (PTAT) and bandgap are also stable and close to pre-rad specifications.



SEE tested with heavy ions up to LET=88 MeV/(mg/cm²) Only fast transients (2-3us), no permanent damage or long-resets

For CERN applications LET=46MeV/(mg/cm²), the transients are smaller than 20% of Vout



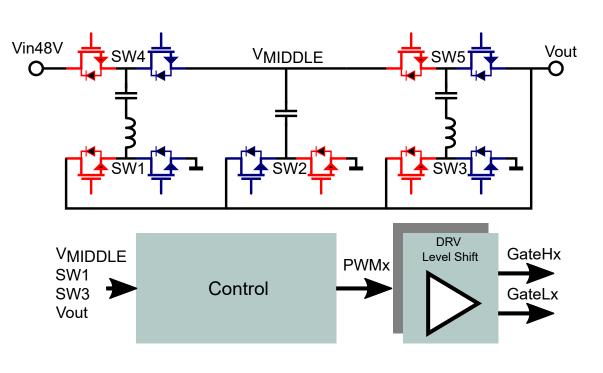
Displacement damage tested separately for the controller and the GaN power stage.

rPOL48V

Key features:

- Resonant topology derived from switched capacitor converter (SCC)

- Standard off-the-shelf inductors
- Standard oπ-the-shell inductors
 Fixed conversion ratio (4-to-1)
- 50A maximum load (600W)
- 50mm x 50mm x 12mm



rPOL48V





§ 92.5

2 90.0

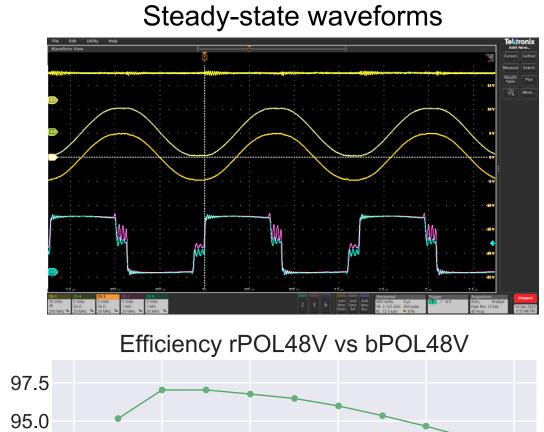
82.5

0.08



rPOL48V prototype with commercial drivers and FPGA-based controller (left). bPOL48V (production grade) (right).

Electrical characterization



Iout [A]

Resonant capacitor voltages
Switching node voltages

Vout

Efficiency greater than 92% at maximum load (50A)

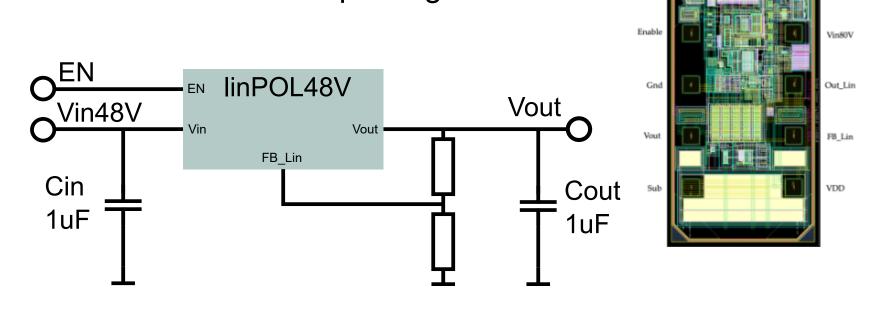
Towards a rad-hard rPOL48V

| ASIC | Techology | Status |
|----------------|---------------------------|--|
| EPC2218 | GaN (EPC) | Radiation tests are on-going, tolerant to $TID > 600Mrad$ |
| linPOL48V | On Semi I3T80 (up to 70V) | In production, tolerant to $TID = 600Mrad$, $LET = 40 MeV cm^2/mg$, $2.23e14^p/_{cm^2}$, $4e14^n/_{cm^2}$ |
| Level shifter | On Semi I3T80 (up to 70V) | Taped out, prototypes will be tested in 2022 |
| GaN driver | On Semi I3T25 (up to 20V) | Taped out, prototypes will be tested in 2022 |
| STC controller | On Semi I3T25 (up to 20V) | Schematic done |

IinPOL48V

Key features:

- Linear regulatorUp to 48V input
- 12V default output voltage (adjustable)
- Enable input and under-voltage lockup
- 200mA continous load (assuming junction temperature is kept below 90°C)
- DFN-8 2mm x 2mm package



Output voltage 13.8 13.7 13.6 13.5 13.4 13.3 13.2 13.1 13.0 0 100 200 300 400 500 600 TID [Mrad]. TIDmax = 590.6Mrad

TID tested up to 600 Mrad without degradation of performance.

SEE tested up to LET=88 MeV/(mg/cm²)
Only fast transients (less than 3us)
Amplitude of transients less than 10%
No permanent damage or long-resets.

DD ok up to 4e14 n/cm² and 2.23e14 p/cm² (25MeV beam, Birmingham).

Summary

Two new Point-of-Load (POL) converters and a linear regulator, suitable for the High Luminosity – Large Hadron Collider (HL-LHC) experiments and for space/avionic applications, were presented. The two DCDC converters, called bPOL48V and rPOL48V, allow a significant improvement in the power delivery requirements as they can provide higher power at an increased input voltage of 48V, compared to existing solutions. The linear regulator, called linPOL48V, can supply up to 200mA with programmable output voltage, from up to 48V input, for low current and noise-sensitive applications.

Rad-hard controller being designed at

| Developement status (Sep. 2022) | | | |
|---------------------------------|---|---|--|
| | Status | Availability | |
| | Fully tested Radiation tolerance OK TID, DD, SEE | Already produced 30 wafers available ~30k samples | |
| | First prototype Tests ongoing Commercial drivers EPGA control | | |





Name

bPOL48V

IinPOL48V

rPOL48V